

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION

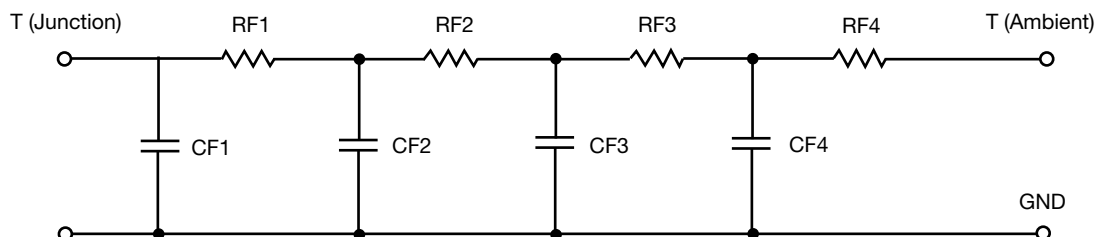


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	10.7093	N/A	3.7706
RT2	39.5822	N/A	13.7556
RT3	10.6596	N/A	5.6364
RT4	49.6244	N/A	17.8015
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	7.3840m	N/A	441.5431u
CT2	24.0152m	N/A	55.3084m
CT3	2.7043m	N/A	128.9292m
CT4	1.0683	N/A	4.3363m

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	13.2298	N/A	4.5018
RF2	29.4118	N/A	18.5492
RF3	22.4321	N/A	12.1346
RF4	44.8724	N/A	6.0216
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	1.2175m	N/A	417.3089u
CF2	7.2923m	N/A	3.1542m
CF3	54.2439m	N/A	26.7069m
CF4	1.1061	N/A	106.8017m

**Note**

N/A indicates not applicable

